# 9-Bit ECL to TTL Translator

The MC10H/100H601 is a 9-bit, dual supply ECL to TTL translator. Devices in the Motorola 9-bit translator series utilize the 28-lead PLCC for optimal power pinning, signal flow-through and electrical performance.

The devices feature a 48 mA TTL output stage, and AC performance is specified into both a 50 pF and 200 pF load capacitance. For the 3-state output disable, both ECL and TTL control inputs are provided, allowing maximum design flexibility.

The 10H version is compatible with MECL 10H ECL logic levels. The 100H version is compatible with 100K levels.

- 9-Bit Ideal for Byte-Parity Applications
- 3–State TTL Outputs
- Flow-Through Configuration
- Extra TTL and ECL Power Pins to Minimize Switching Noise
- ECL and TTL 3-State Control Inputs
- Dual Supply
- 4.8 ns Max Delay into 50 pF, 9.6 ns into 200 pF (all outputs switching)

**OEECL** 

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OETTL

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• PNP TTL Inputs for Low Loading

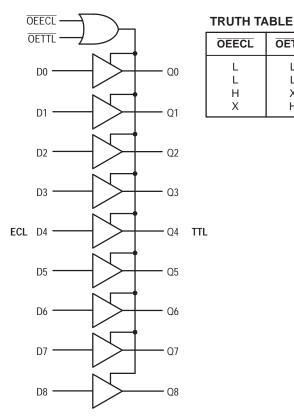


Figure 1. Logic Diagram



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PLCC-28 **FN SUFFIX CASE 776** 

#### **MARKING DIAGRAM**



= Assembly Location

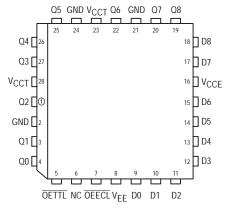
= Wafer Lot

YY = Year

WW = Work Week

#### **PIN NAMES**

PIN	FUNCTION
GND VCCE VCCT VEE D0-D8 Q0-Q8 OEECL OETTL	TTL Ground (0 V) ECL V <sub>CC</sub> (0 V) TTL Supply (+5.0 V) ECL Supply (-5.2/-4.5 V) Data Inputs (ECL) Data Outputs (TTL) 3-State Control (ECL) 3-State Control (TTL)



Pinout: 28-Lead PLCC (Top View)

#### **ORDERING INFORMATION**

Device	Package	Shipping
MC10H601FN	PLCC-28	37 Units/Rail
MC100H601FN	PLCC-28	37 Units/Rail

10H ECL DC CHARACTERISTICS:  $V_{CCT}$  = 5.0 V  $\pm$  10%;  $V_{EE}$  = -5.2 V  $\pm$  5%

		0°C		25°C		85°C			
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Unit	Condition
IEE	Power Supply Current		-51		-51		-51	mA	
INH INL	Input HIGH Current Input LOW Current	0.5	225	0.5	145	0.5	145	μA μA	
V <sub>IH</sub> V <sub>IL</sub>	Input HIGH Voltage Input LOW Voltage	-1170 -1950	-840 -1480	-1130 -1950	-810 -1480	-1060 -1950	-720 -1445	mV	

#### 100H ECL DC CHARACTERISTICS: $V_{CCT}$ = 5.0 V $\pm$ 10%; $V_{EE}$ = -4.2 V to -5.5 V

		0°C		25°C		85°C			
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Unit	Condition
IEE	Power Supply Current		-51		-51		-53	mA	
INH INL	Input HIGH Current Input LOW Current	0.5	225	0.5	145	0.5	145	μA μA	
VIH VIL	Input HIGH Voltage Input LOW Voltage	-1165 -1810	-880 -1475	-1165 -1810	-880 -1475	-1165 -1810	-880 -1475	mV	

TTL DC CHARACTERISTICS:  $V_{CCT}$  = 5.0 V ± 10%;  $V_{EE}$  = -5.2 V ± 5% (10H version);  $V_{EE}$  = -4.2 V to -5.5 V (100H version)

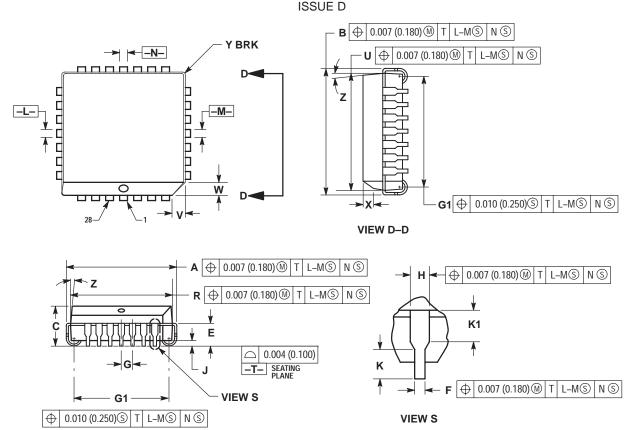
		0°C		25	°C	85°C			
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Unit	Condition
Іссн	Power Supply Current		110		110		110	mA	
ICCL			110		110		110		
ICCZ	Power Supply Current		105		105		105		
lн	Input HIGH Current		20 100		20 100		20 100	μА	V <sub>IN</sub> = 2.7 V V <sub>IN</sub> = 7.0 V
I <sub>IL</sub>	Input LOW Current		-0.6		-0.6		-0.6	mA	V <sub>IN</sub> = 0.5 V
los	Output Short Circuit Current	-100	-225	-100	-225	-100	-225	mA	V <sub>OUT</sub> = 0 V
IOZH IOZL	Output Disable Current HIGH Output Disable Current LOW	-50	50	-50	50	-50	50	μА	V <sub>OUT</sub> = 2.7 V V <sub>OUT</sub> = 0.5 V
VIHT VILT	Input HIGH Voltage Input LOW Voltage	2.0	0.8	2.0	0.8	2.0	0.8	V	
VOHT	Output HIGH Voltage	2.5 2.0		2.5 2.0		2.5 2.0		V	I <sub>OH</sub> = -3.0 mA I <sub>OH</sub> = -15 mA
VOLT	Output LOW Voltage		0.55		0.55		0.55	V	I <sub>OL</sub> = 48 mA
VIK	Input Clamp Voltage		-1.2		-1.2		-1.2	V	I <sub>IN</sub> = -18 mA

AC CHARACTERISTICS:  $V_{CCT}$  = 5.0 V  $\pm$  10%;  $V_{EE}$  = -5.2 V  $\pm$  5% (10H version);  $V_{EE}$  = -4.2 V to -5.5 V (100H version)

			0°C		25	°C	85°C			
Symbol	Parameter		Min	Max	Min	Max	Min	Max	Unit	Condition
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay to Output		1.7 3.4	4.8 9.6	1.7 3.4	4.8 9.6	1.7 3.4	4.8 9.6	ns ns	C <sub>L</sub> = 50 pF C <sub>L</sub> = 200 pF
<sup>t</sup> PLZ <sup>t</sup> PHZ	Output Disable Time	OEECL	3.7 5.4	6.5 13	3.7 5.4	6.5 13	3.7 5.4	6.5 13	ns ns	C <sub>L</sub> = 50 pF C <sub>L</sub> = 200 pF
<sup>t</sup> PLZ <sup>t</sup> PHZ		OETTL	4.3 7.0	7.5 15	4.3 7.0	7.5 15	4.3 7.0	7.5 15	ns ns	C <sub>L</sub> = 50 pF C <sub>L</sub> = 200 pF
<sup>t</sup> PZL <sup>t</sup> PZH	Output Enable Time	OEECL	3.5 5.0	6.0 12	3.5 5.0	6.0 12	3.5 5.0	6.0 12	ns ns	C <sub>L</sub> = 50 pF C <sub>L</sub> = 200 pF
<sup>t</sup> PZL <sup>t</sup> PZH		OETTL	4.2 6.0	7.0 14	4.2 6.0	7.0 14	4.2 6.0	7.0 14	ns ns	C <sub>L</sub> = 50 pF C <sub>L</sub> = 200 pF
t <sub>R</sub>	Output Rise/Fall Time 1.0 V-2.0 V			1.2 3.0		1.2 3.0		1.2 3.0	ns ns	C <sub>L</sub> = 50 pF C <sub>L</sub> = 200 pF

#### **PACKAGE DIMENSIONS**

#### PLCC-28 **FN SUFFIX** PLASTIC PLCC PACKAGE CASE 776-02



- NOTES:
  1. DATUMS -L-, -M-, AND -N- DETERMINED 1. DATUMS -L., -M., AND -N. DE LERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
  2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T., SEATING PLANE.
  3. DIMENSIONS R AND U DO NOT INCLUDE.
  - MOLD FLASH. ALLOWABLE MOLD FLASH IS
  - 0.010 (0.250) PER SIDE.
- 4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 5. CONTROLLING DIMENSION: INCH.

  6. THE PACKAGE TOP MAY BE SMALLER THAN
- . THE PACKAGE TOP MAY BE SMALLER TH
  THE PACKAGE BOTTOM BY UP TO 0.012
  (0.300). DIMENSIONS R AND U ARE
  DETERMINED AT THE OUTERMOST
  EXTREMES OF THE PLASTIC BODY
  EXCLUSIVE OF MOLD FLASH, TIE BAR
  BURRS, GATE BURRS AND INTERLEAD
  FLASH, BUT INCLUDING ANY MISMATCH
  ETMEEN THE TOP AND POTTOM OF THE BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.485	0.495	12.32	12.57	
В	0.485	0.495	12.32	12.57	
С	0.165	0.180	4.20	4.57	
Ε	0.090	0.110	2.29	2.79	
F	0.013	0.019	0.33	0.48	
G	0.050	) BSC	1.27	BSC	
Н	0.026	0.032	0.66	0.81	
J	0.020		0.51		
K	0.025		0.64		
R	0.450	0.456	11.43	11.58	
U	0.450	0.456	11.43	11.58	
V	0.042	0.048	1.07	1.21	
W	0.042	0.048	1.07	1.21	
Х	0.042	0.056	1.07	1.42	
Υ		0.020		0.50	
Z	2°	10°	2°	10°	
G1	0.410	0.430	10.42	10.92	
K1	0.040		1.02		

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